NSN 5962-01-163-4173

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-163-4173

Body Length:
Between 1.235 inches and 1.290 inches
Body Width:
Between 0.510 inches and 0.540 inches
Body Height:
Between 0.140 inches and 0.170 inches
Operating Tempurature Range:
-0.0/+75.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Programmable and bipolar and schottky and 3-state output
Inclosure Material:
Plastic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
mpar on our random
14 input
14 input
14 input Terminal Surface Treatment:
14 input Terminal Surface Treatment: Solder
14 input Terminal Surface Treatment: Solder Voltage Rating And Type Per Characteristic:
14 input Terminal Surface Treatment: Solder Voltage Rating And Type Per Characteristic: 5.5 volts power source
14 input Terminal Surface Treatment: Solder Voltage Rating And Type Per Characteristic: 5.5 volts power source Time Rating Per Chacteristic:
14 input Terminal Surface Treatment: Solder Voltage Rating And Type Per Characteristic: 5.5 volts power source Time Rating Per Chacteristic: 35.00 nanoseconds propagation delay time, low to high level output
14 input Terminal Surface Treatment: Solder Voltage Rating And Type Per Characteristic: 5.5 volts power source Time Rating Per Chacteristic: 35.00 nanoseconds propagation delay time, low to high level output Memory Device Type:
14 input Terminal Surface Treatment: Solder Voltage Rating And Type Per Characteristic: 5.5 volts power source Time Rating Per Chacteristic: 35.00 nanoseconds propagation delay time, low to high level output Memory Device Type: Rom
Terminal Surface Treatment: Solder Voltage Rating And Type Per Characteristic: 5.5 volts power source Time Rating Per Chacteristic: 35.00 nanoseconds propagation delay time, low to high level output Memory Device Type: Rom Terminal Type And Quantity:
Terminal Surface Treatment: Solder Voltage Rating And Type Per Characteristic: 5.5 volts power source Time Rating Per Chacteristic: 35.00 nanoseconds propagation delay time, low to high level output Memory Device Type: Rom Terminal Type And Quantity: 24 printed circuit
Terminal Surface Treatment: Solder Voltage Rating And Type Per Characteristic: 5.5 volts power source Time Rating Per Chacteristic: 35.00 nanoseconds propagation delay time, low to high level output Memory Device Type: Rom Terminal Type And Quantity: 24 printed circuit Shelf Life:
Terminal Surface Treatment: Solder Voltage Rating And Type Per Characteristic: 5.5 volts power source Time Rating Per Chacteristic: 35.00 nanoseconds propagation delay time, low to high level output Memory Device Type: Rom Terminal Type And Quantity: 24 printed circuit Shelf Life: N/a
Terminal Surface Treatment: Solder Voltage Rating And Type Per Characteristic: 5.5 volts power source Time Rating Per Chacteristic: 35.00 nanoseconds propagation delay time, low to high level output Memory Device Type: Rom Terminal Type And Quantity: 24 printed circuit Shelf Life: N/a
Terminal Surface Treatment: Solder Voltage Rating And Type Per Characteristic: 5.5 volts power source Time Rating Per Chacteristic: 35.00 nanoseconds propagation delay time, low to high level output Memory Device Type: Rom Terminal Type And Quantity: 24 printed circuit Shelf Life: N/a Unit Of Measure:

A458a0